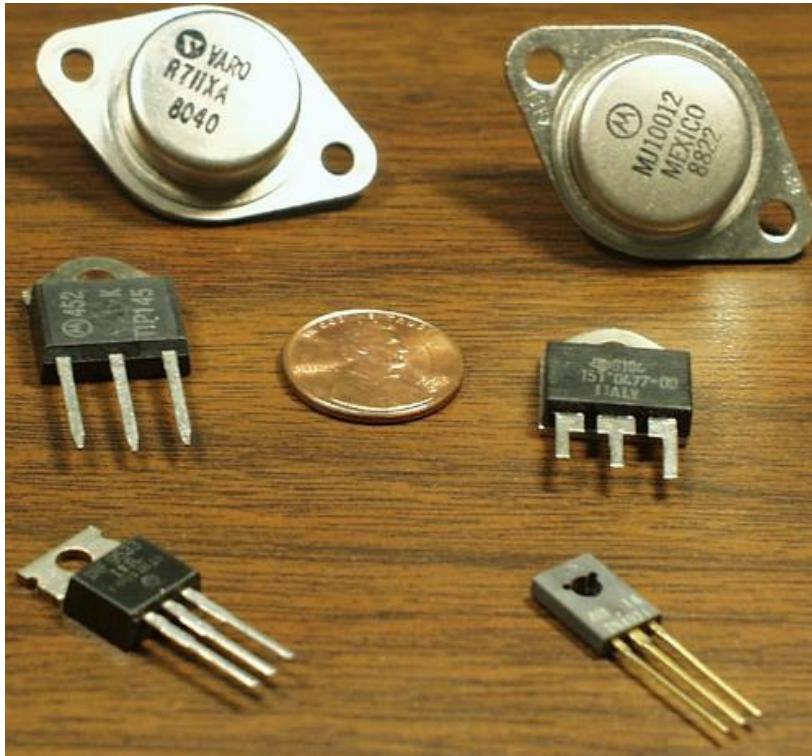


MOSFET Logic Circuits

TRANSISTORS

- **Active** semiconductor devices (with three terminals)
- Operating **principle**: using a **voltage** between two terminals (command) **to control the current** through the third terminal.
- Transistors: ***voltage-controlled current sources***



Discrete
transistors

TRANSISTORS

Transistors: essential components of every electronic circuit

Integrated transistors - digital integrated circuit

MOS transistor (T) count (processor)

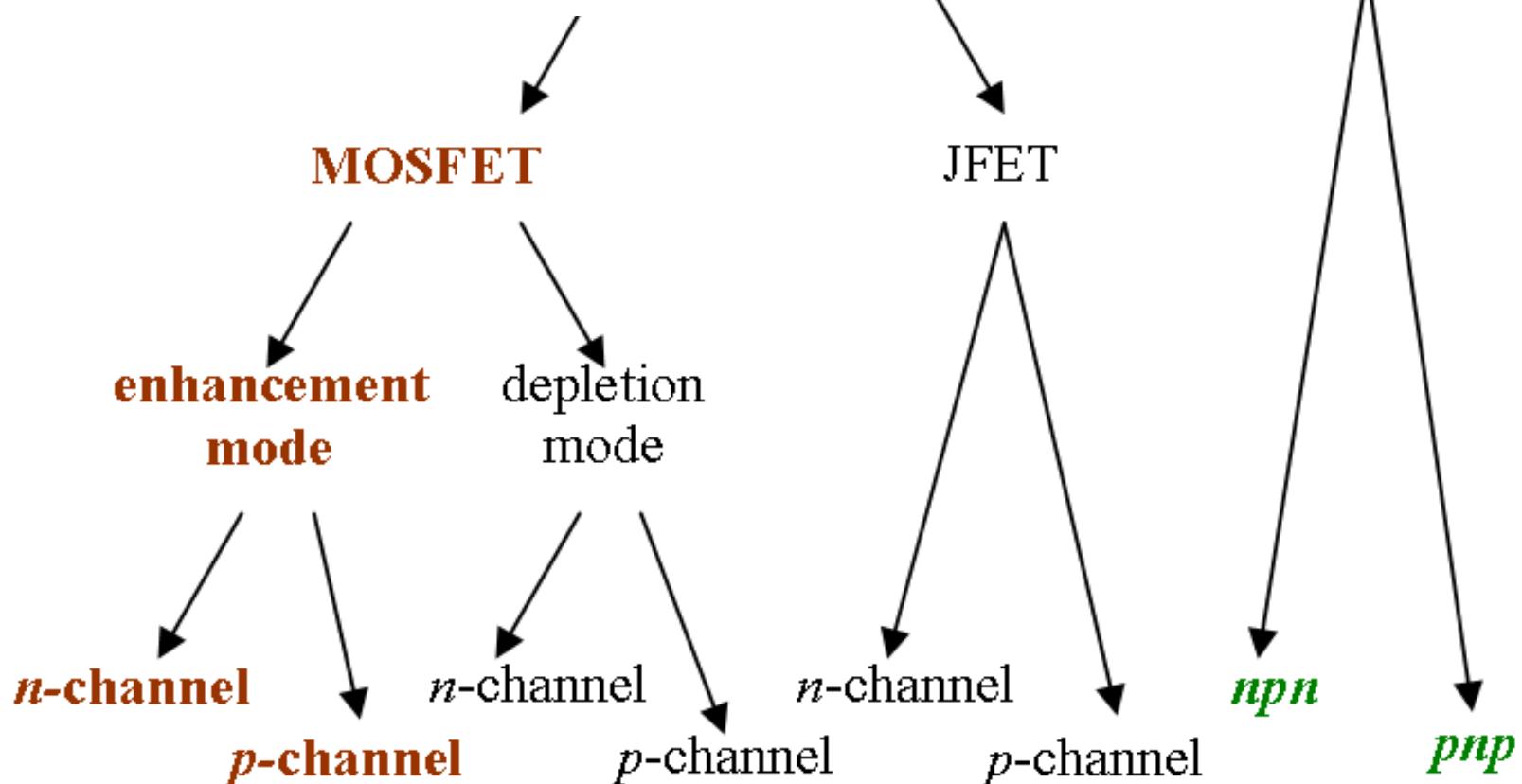
- Intel 4004 (4-bit), 1971, 10µ, 12mm², **2,250 T**
- Pentium 4 Prescott (32-bit) 2004, 90nm, 110mm² **112,000,000 T**
- Core i7 Broadwell-E (64-bit), 2016, 14nm, 246mm², **3,200,000,000 T**
- Apple A12 (hexa-core ARM64), 2018, 7nm, 83.27mm², **6,900,000,000 T**
- AMD Epyc Rome (64-bit), 2019, 7&12nm, 1088 mm², **39,540,000,000 T**
- Apple M1 Max (10-core, 64-bit), 2021, 5nm, **57,000,000,000 T**
- GH100 Hopper GPU, 2022, 4nm, 814mm², **80,000,000,000 T**

Transistor types

Metal-Oxide-Semiconductor Field-Effect Transistors

MOSFET

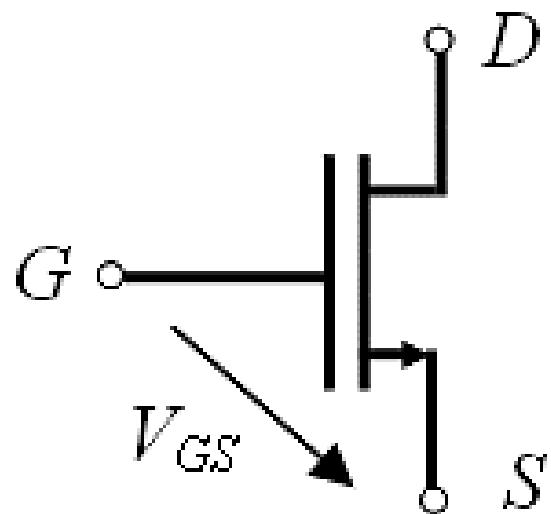
Transistors
field-effect FET
Bipolar Junction Transistors
bipolar BJT



Symbols of MOSFET

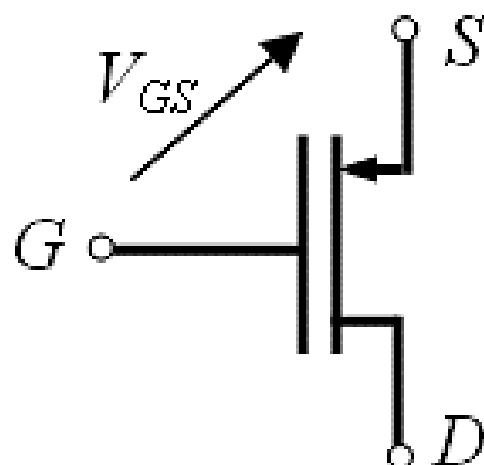
n -channel
enhancement-type
MOSFET

n - type



p -channel
enhancement-type
MOSFET

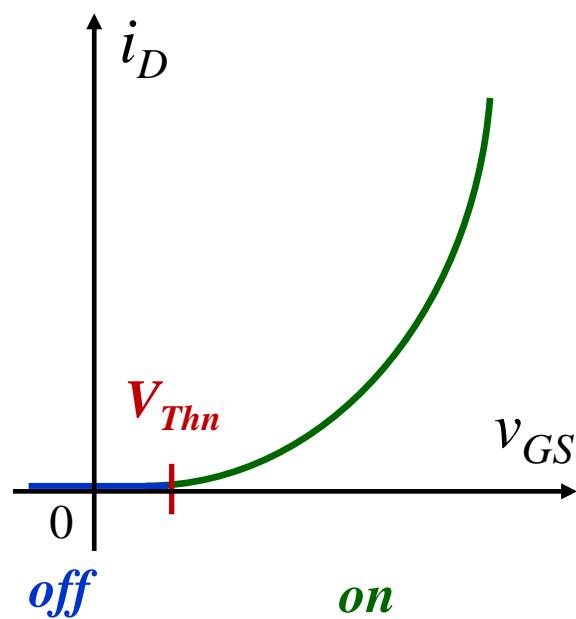
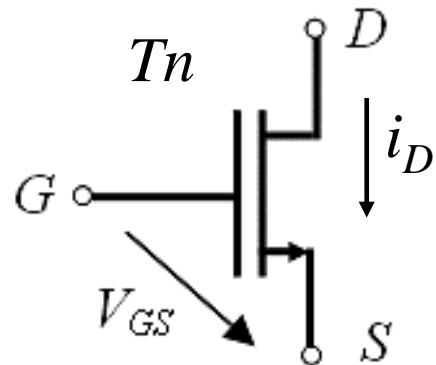
p - type



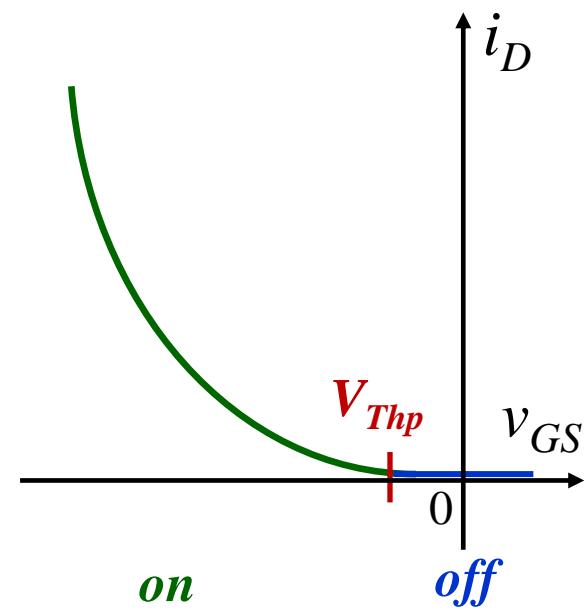
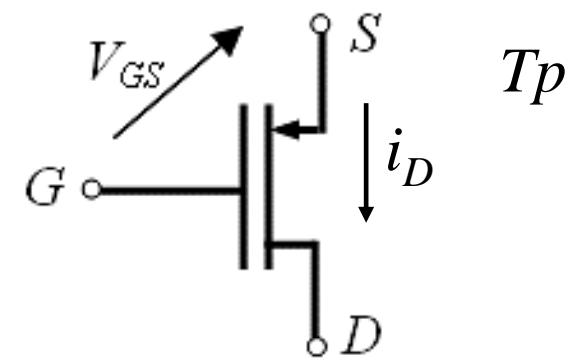
G - gate
D - drain
S - source

Operation of MOSFET

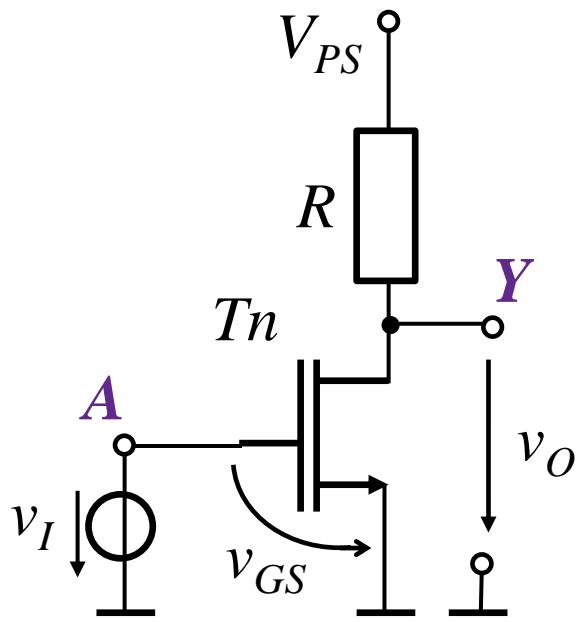
n-channel
enhancement-type **MOSFET**



p-channel
enhancement-type **MOSFET**

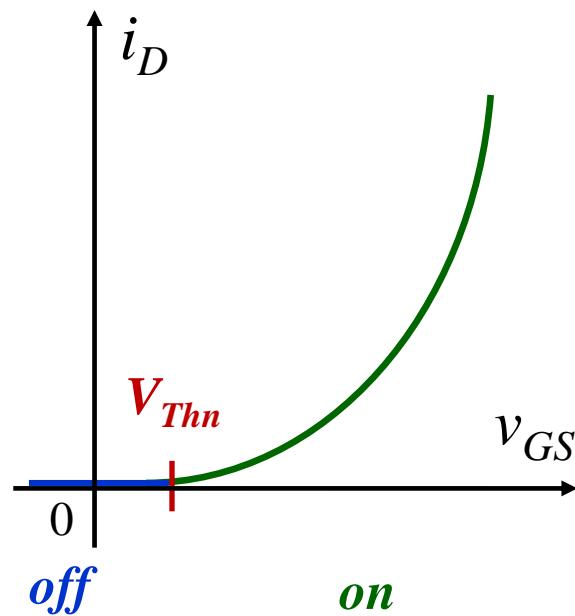


Logic circuit with Tn



$$v_{GS} = v_I$$

$$v_I \in \{0, V_{PS}\}$$



Operating table

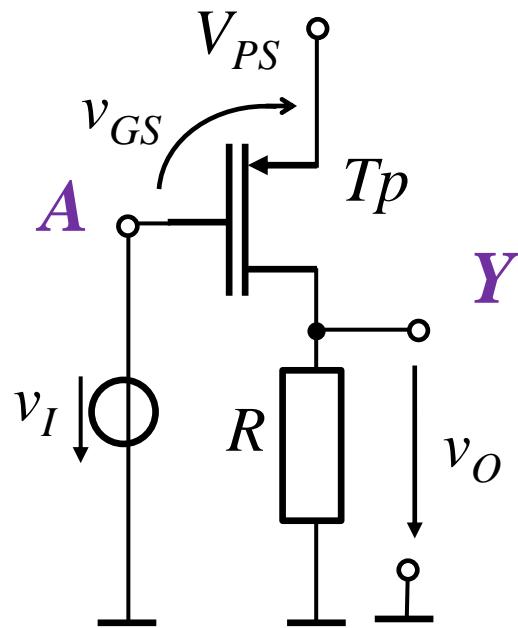
v_I	v_{GS}	Tn	v_O
0	0 ($< v_{Thn}$)	off (open-circuit)	V_{PS}
V_{PS}	V_{PS} ($>> v_{Thn}$)	on (short-circuit)	0

Truth table

A	Y
0	1
1	0

NOT

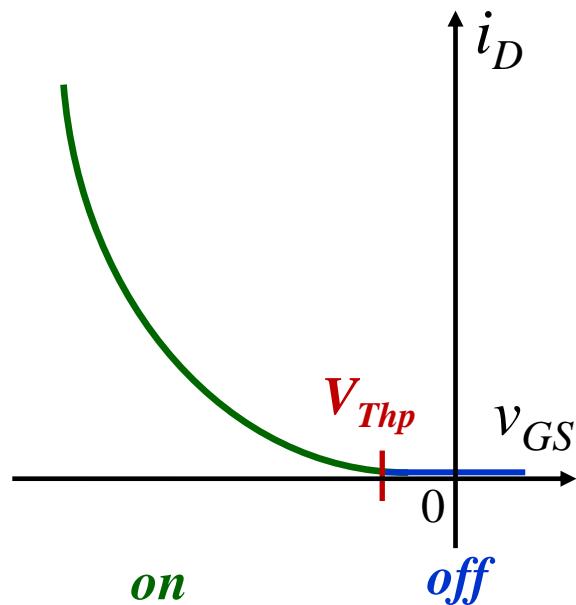
Logic circuit with Tp



$$v_{GS} = v_I - V_{PS}$$

$$v_I \in \{0, V_{PS}\}$$

v_I	v_{GS}	Tn	v_O
0	$-V_{PS}$ $(<< v_{Thp})$	<i>on</i> (short-circuit)	V_{PS}
V_{PS}	0 $(> v_{Thn})$	<i>off</i> (open-circuit)	0



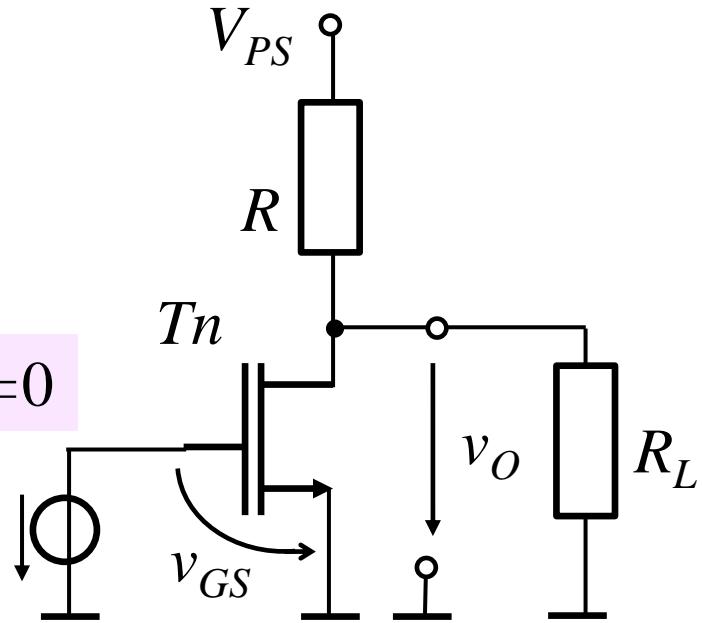
Operating table

Truth table

A	Y
0	1
1	0

NOT

Critical analysis of the NOT logic circuit with T_n and R

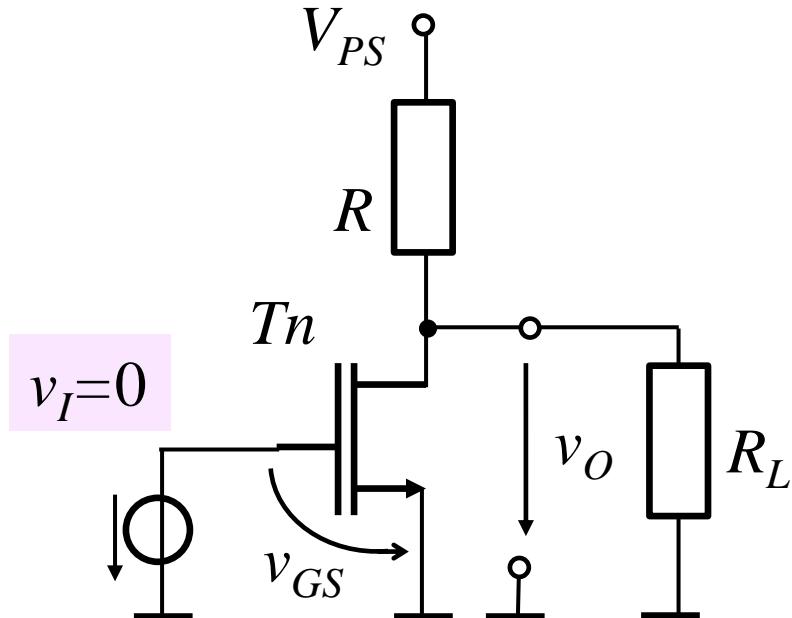


$$v_O = \frac{R_L}{R_L + R} V_{PS}$$

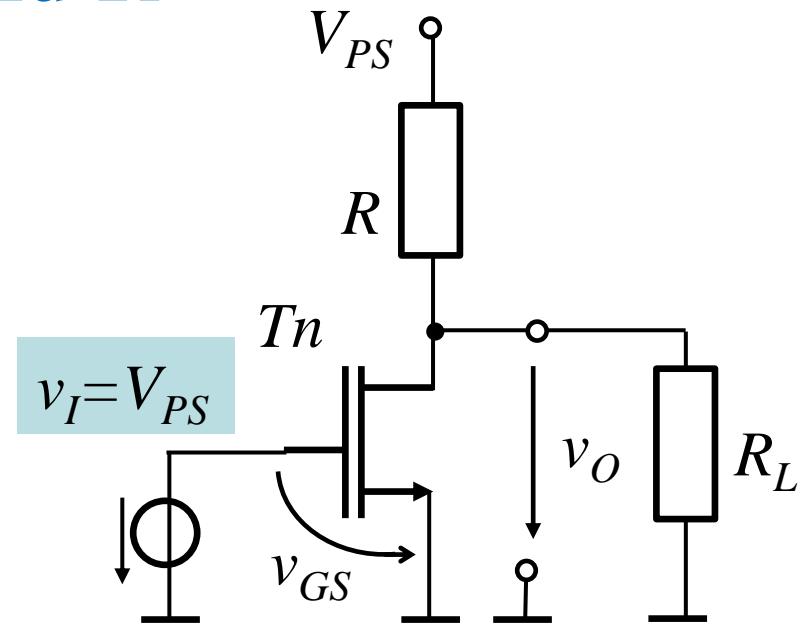
Disadvantage elimination:

R as small as possible, ideal $R \rightarrow 0$

Critical analysis of the NOT logic circuit with T_n and R



$$v_O = \frac{R_L}{R_L + R} V_{PS}$$



$$P_{PS} = \frac{V_{PS}^2}{R}$$

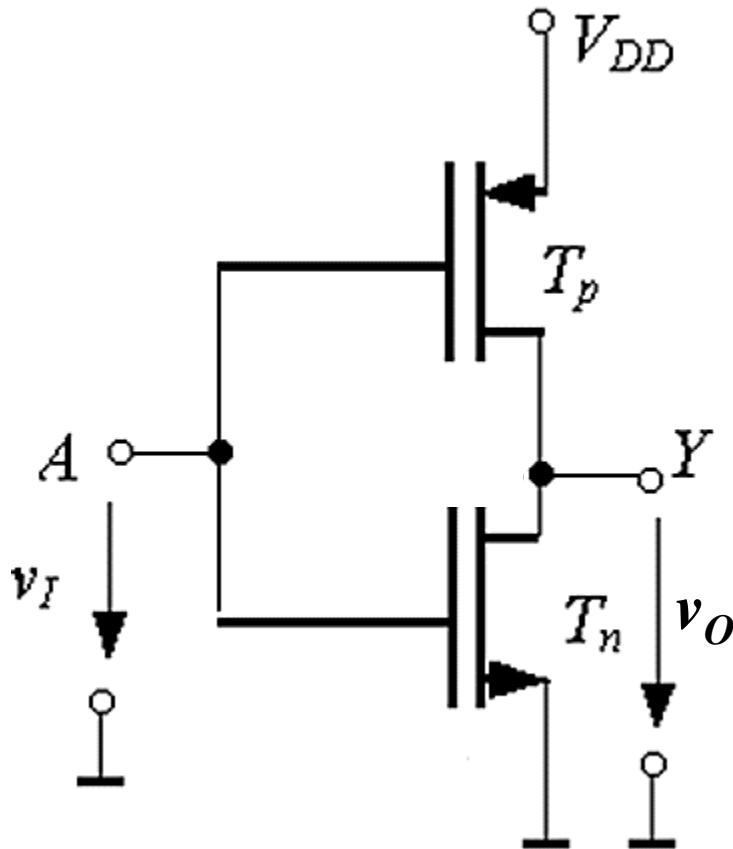
Disadvantage elimination:

R as small as possible, ideal $R \rightarrow 0$

R as large as possible, ideal $R \rightarrow \infty$

Solution?

CMOS Logic Inverter

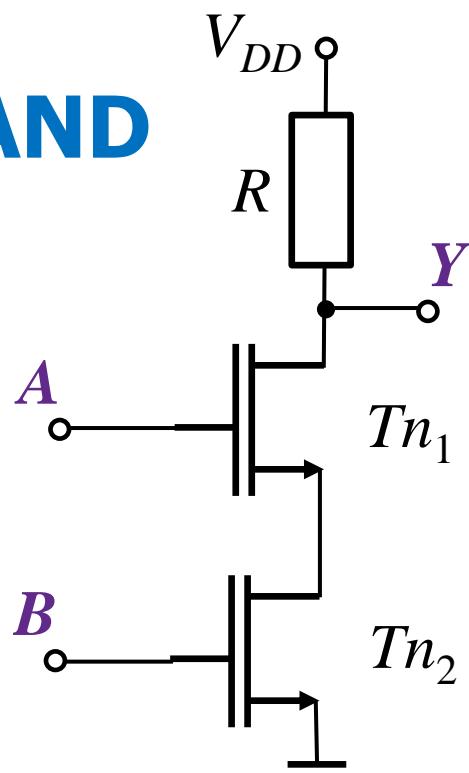


v_I	T_n	T_p	v_O
0V	(off)	(on)	$\approx V_{DD}$
V_{DD}	(on)	(off)	$\approx 0V$

A	Y
0	1
1	0

CMOS – Complementary MOSFET

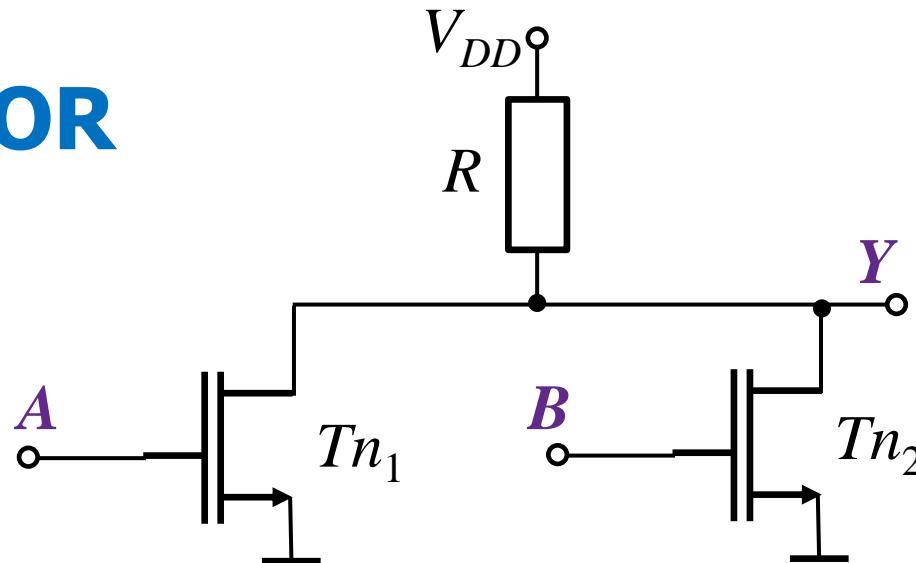
NAND



A	B	T_{n1}	T_{n2}	$Y = \overline{A \cdot B}$
0	0	(off)	(off)	1
0	1	(off)	(on)	1
1	0	(on)	(off)	1
1	1	(on)	(on)	0

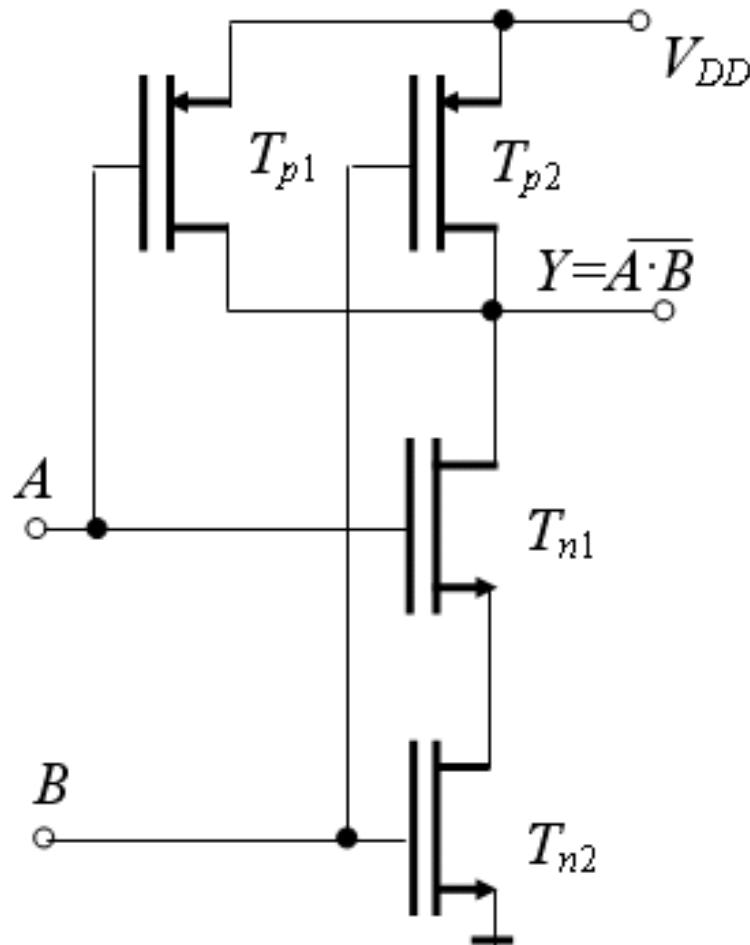
How can we eliminate the disadvantages due to the presence of R ?

NOR



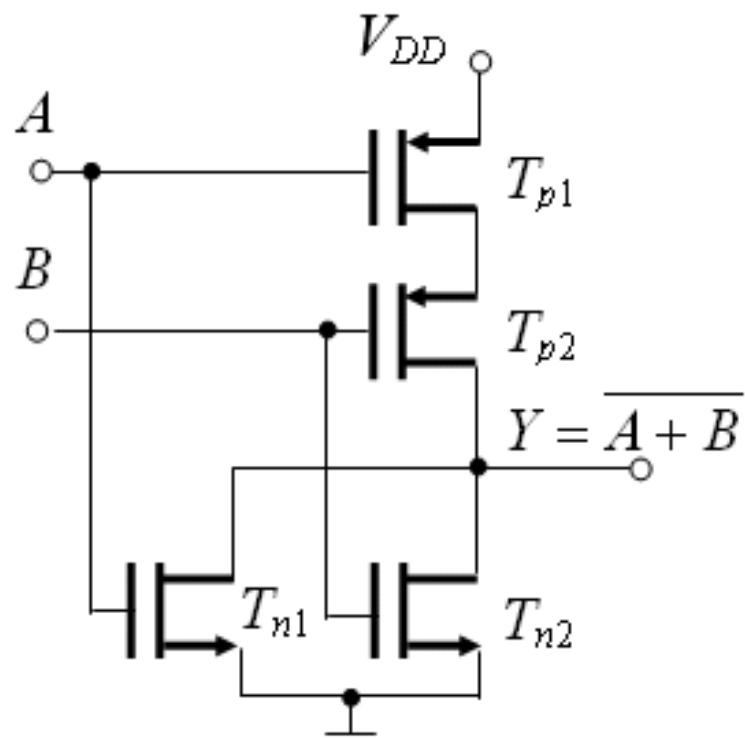
A	B	T_{n1}	T_{n2}	$Y = \overline{A + B}$
0	0	(off)	(off)	1
0	1	(off)	(on)	0
1	0	(on)	(off)	0
1	1	(on)	(on)	0

CMOS NAND

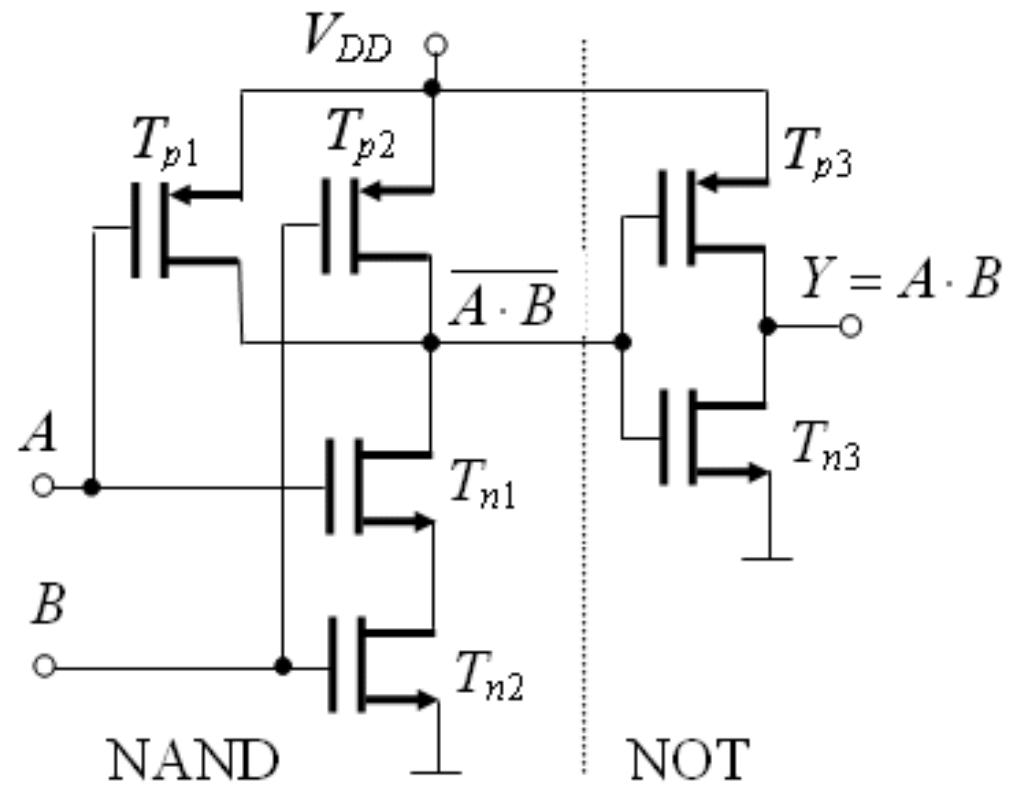


A	B	T_{n1}	T_{n2}	T_{P1}	T_{P2}	$Y = \overline{A \cdot B}$
0	0	(off)	(off)	(on)	(on)	1
0	1	(off)	(on)	(on)	(off)	1
1	0	(on)	(off)	(off)	(on)	1
1	1	(on)	(on)	(off)	(off)	0

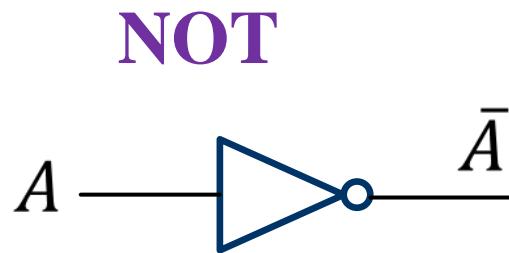
CMOS NOR



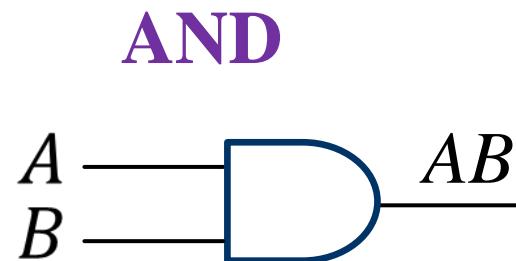
CMOS AND



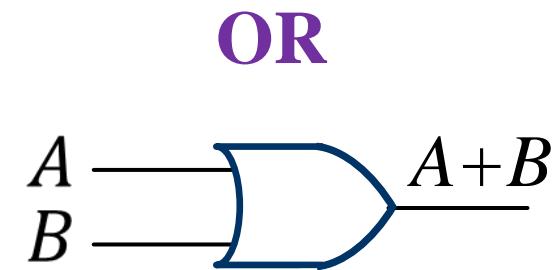
Logic Gates



A	\bar{A}
0	1
1	0



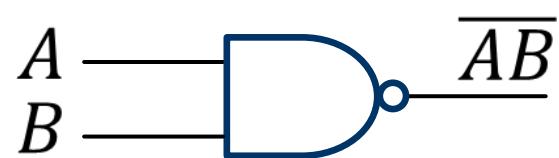
A	B	AB
0	0	0
0	1	0
1	0	0
1	1	1



A	B	$A + B$
0	0	0
0	1	1
1	0	1
1	1	1

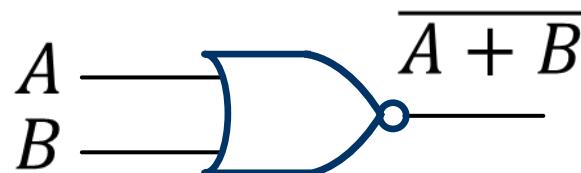
Logic Gates – cont.

NAND



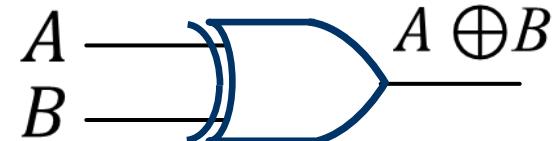
A	B	\overline{AB}
0	0	1
0	1	1
1	0	1
1	1	0

NOR



A	B	$\overline{A + B}$
0	0	1
0	1	0
1	0	0
1	1	0

XOR



A	B	$A \oplus B$
0	0	0
0	1	1
1	0	1
1	1	0

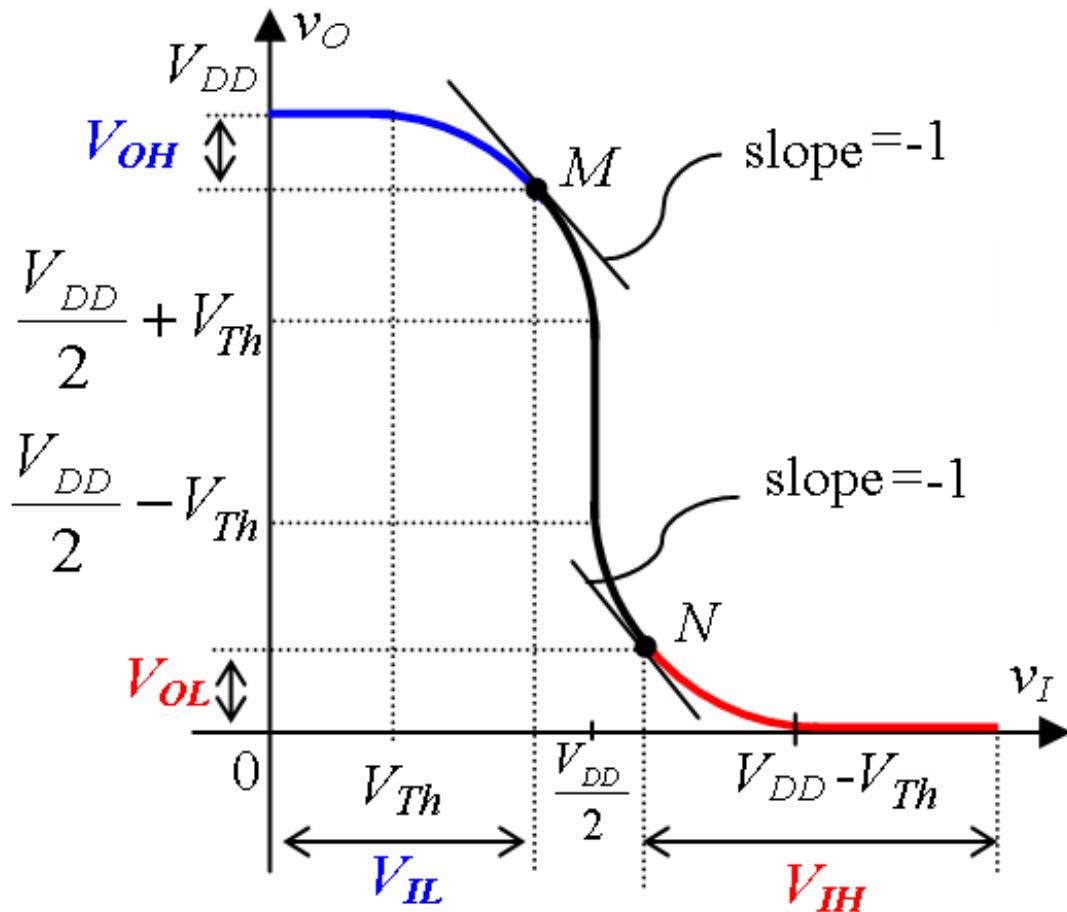
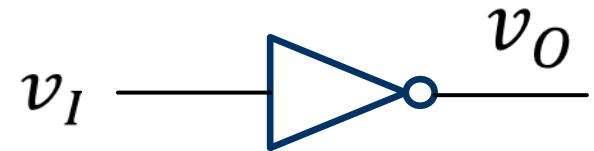
Problem

Use logic gates to implement the logic function:

$$Y = \overline{AB} + A\bar{C}$$

What is the truth table?

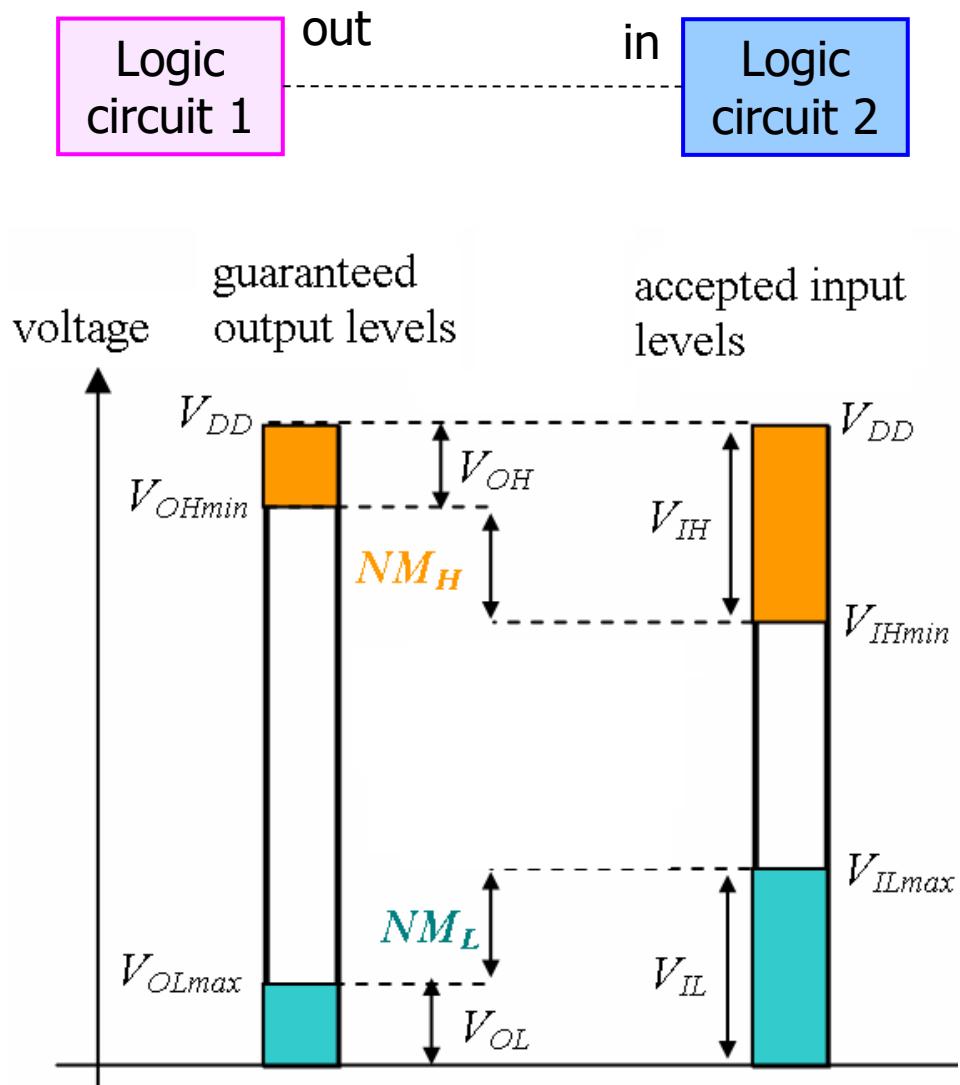
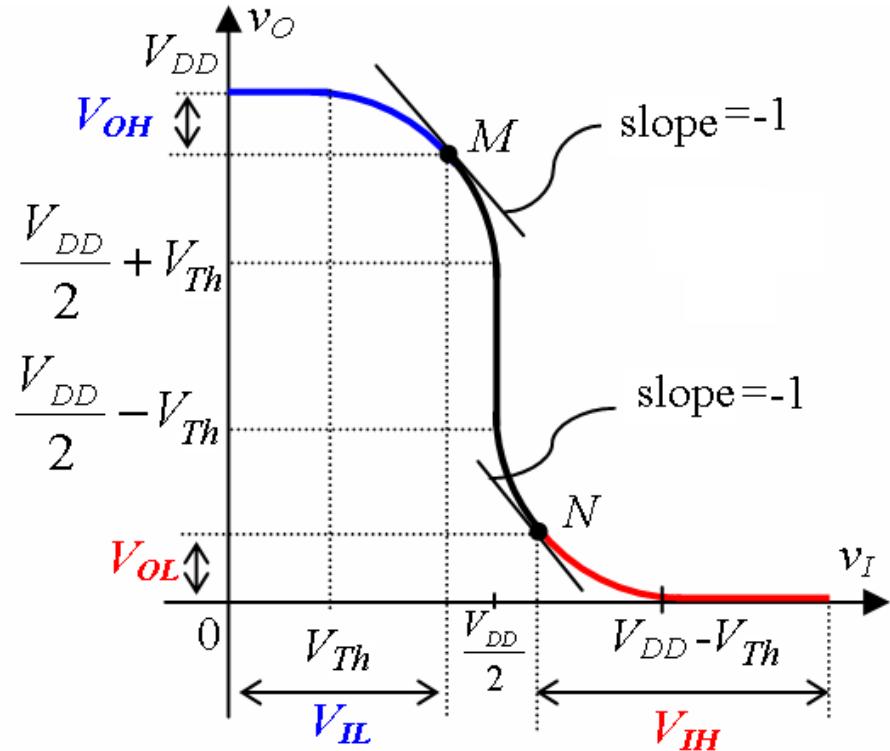
Transfer characteristic of the CMOS inverter



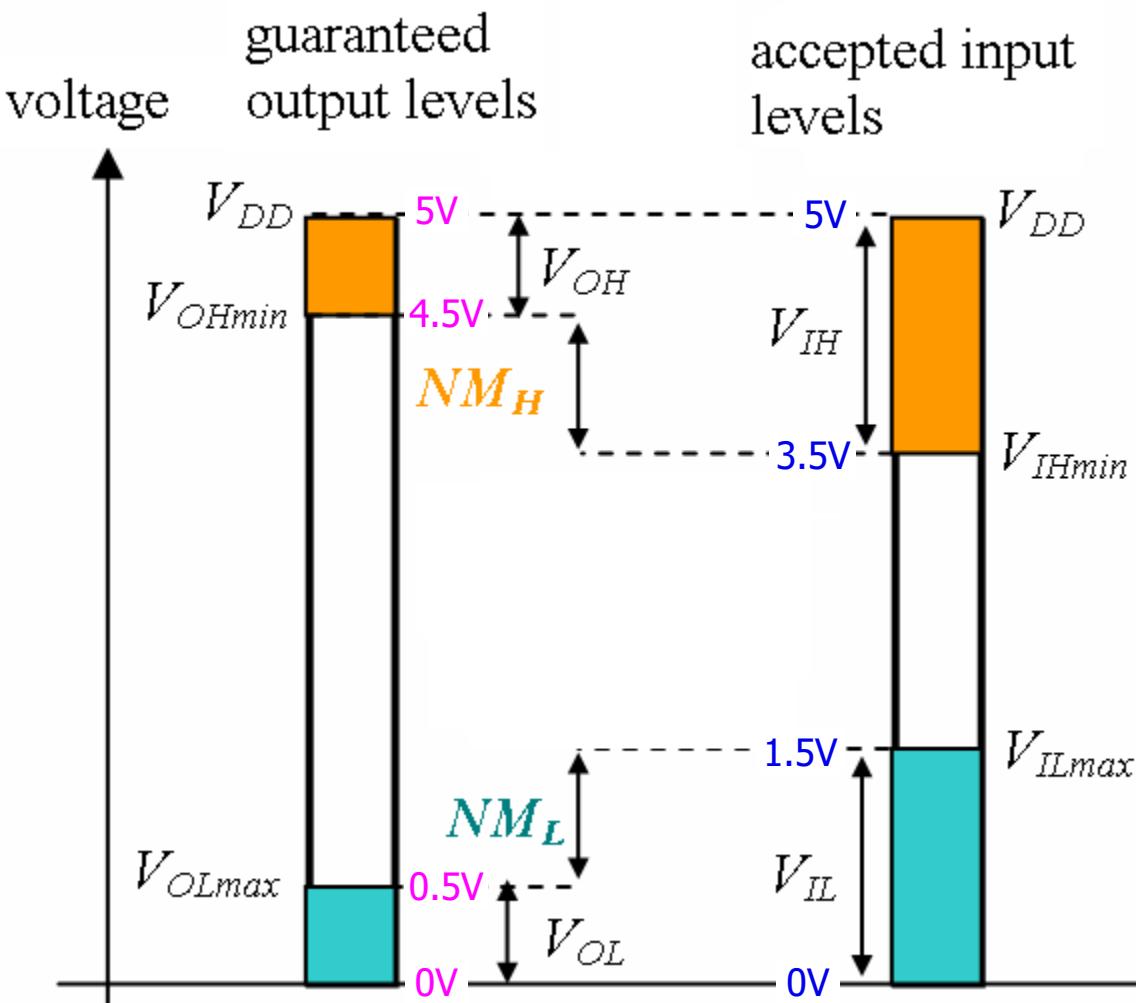
$$v_I \in [0; V_{DD}]$$

$$v_O \in [0; V_{DD}]$$

Noise margins



Noise margins - cont.



$$NM_H = V_{OH\min} - V_{IH\min}$$

$$NM_L = V_{IL\max} - V_{OL\max}$$

Voltage levels and noise margins for *CMOS* logic family supplied at +5V

$$NM_L = 1.5V - 0.5V = 1V$$

$$NM_H = 4.5V - 3.5V = 1V$$